



## PE2302DF N-Channel Enhancement Mode Power MOSFET

### PE2302DF Description

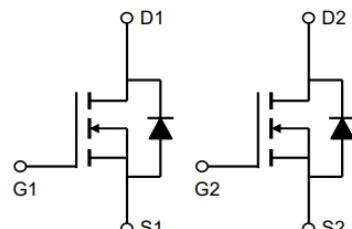
The PE2302DF uses advanced trench technology to provide excellent  $R_{DS(ON)}$  and low gate charge. It can be used in a wide variety of applications.

### PE2302DF General Features

- $V_{DS} = 20V$ ,  $I_D = 5A$
- $R_{DS(ON)} < 36m\Omega$  @  $V_{GS}=4.5V$
- $R_{DS(ON)} < 48m\Omega$  @  $V_{GS}=2.5V$
- $R_{DS(ON)} < 80m\Omega$  @  $V_{GS}=1.8V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

### PE2302DF Application

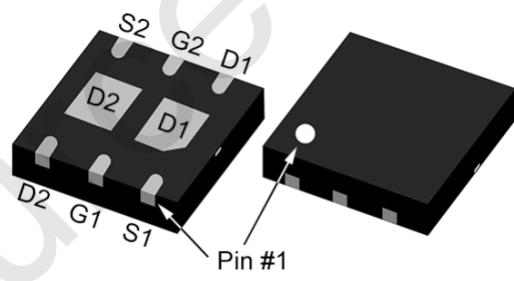
- PWM applications
- Load switch



Schematic diagram

Product Code 2302D  
XXXX Lot No.

Marking and pin assignment



DFN2x2-6L

### PE2302DF Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Drain Current-Continuous	$I_D$	5	A
Drain Current-Continuous (TA=70°C)	$I_D$	4.2	A
Pulsed Drain Current (Note 1)	$I_{DM}$	20	A
Maximum Power Dissipation	$P_D$	1.5	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	°C

### PE2302DF Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	83	°C/W
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**PE2302DF Electrical Characteristics (TA=25°C unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>On Characteristics (Note 3)</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	0.7	1	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=4.5V, I_D=2A$	-	30	36	$m\Omega$
		$V_{GS}=2.5V, I_D=1.5A$	-	40	48	$m\Omega$
		$V_{GS}=1.8V, I_D=1A$		58	80	$m\Omega$
<b>Dynamic Characteristics (Note 4)</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V, F=1.0MHz$	-	330	-	pF
Output Capacitance	$C_{oss}$		-	50	-	pF
Reverse Transfer Capacitance (Note 4)	$C_{rss}$		-	40	-	pF
<b>Switching Characteristics</b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=2A, V_{GS}=4.5V, R_G=6\Omega$	-	10	-	nS
Turn-on Rise Time	$t_r$		-	50	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	17	-	nS
Turn-Off Fall Time	$t_f$		-	10	-	nS
Total Gate Charge	$Q_g$	$V_{DS}=10V, I_D=2A, V_{GS}=4.5V$	-	4	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.65	-	nC
Gate-Drain Charge	$Q_{gd}$		-	1.2	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$V_{SD}$	$V_{GS}=0V, I_s=1A$	-	-	1.2	V
Diode Forward Current (Note 2)	$I_s$		-	-	5	A

**Notes:**

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to product.



### PE2302DF Typical Electrical and Thermal Characteristics

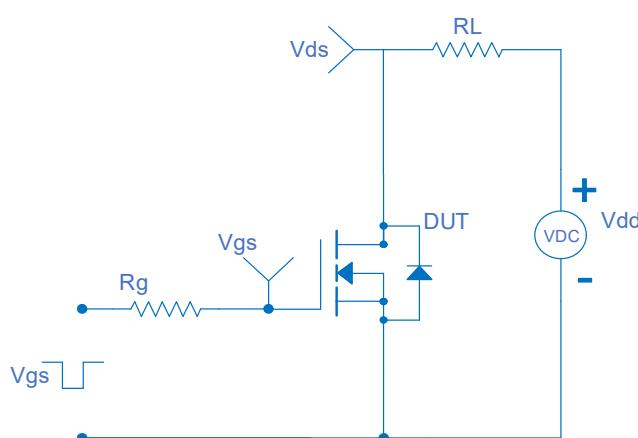


Figure 1 Switching Test Circuit

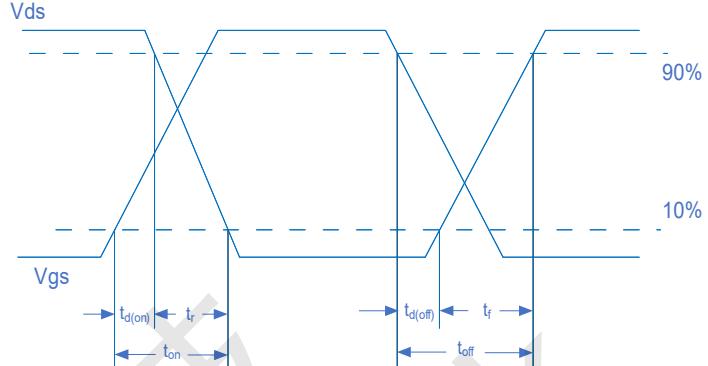
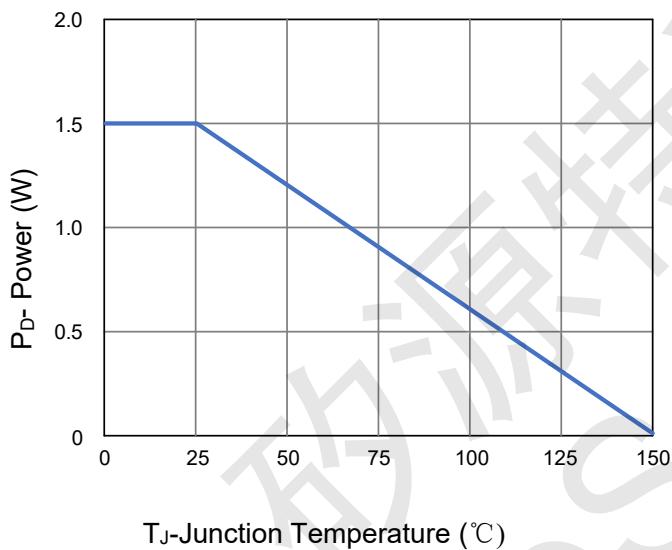
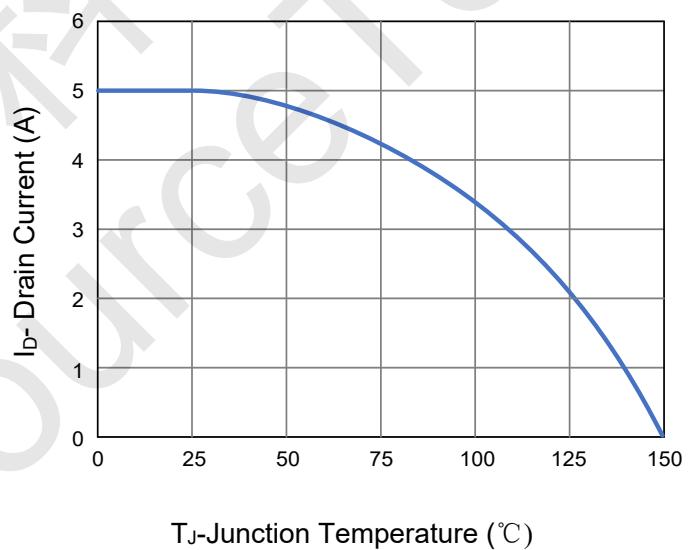


Figure 2 Switching Waveform



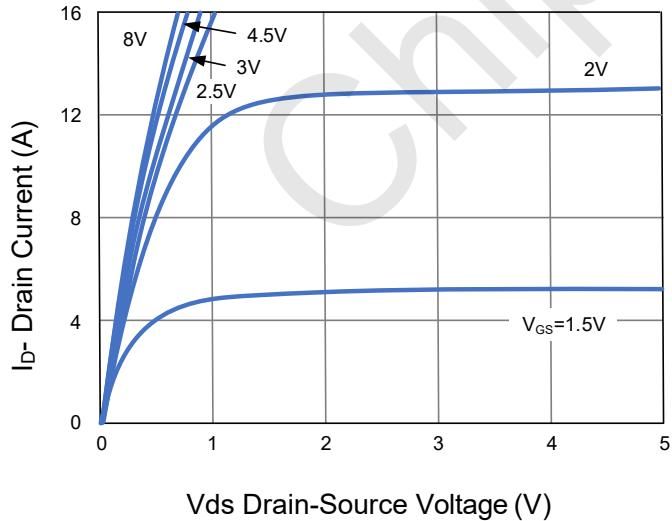
T<sub>J</sub>-Junction Temperature (°C)

Figure 3 Power Dissipation



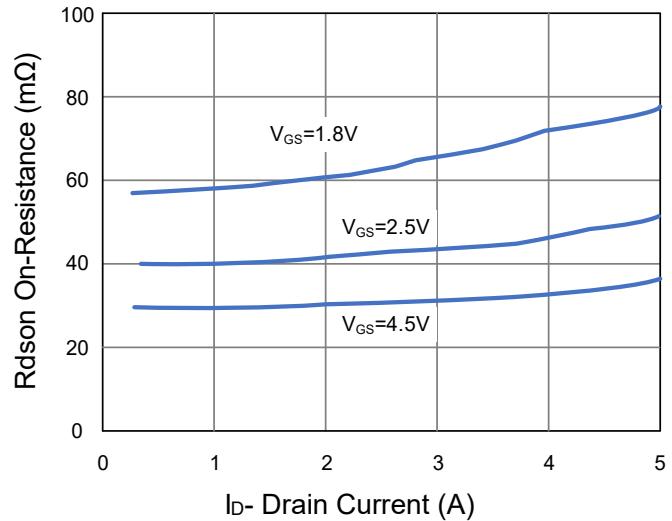
T<sub>J</sub>-Junction Temperature (°C)

Figure 4 Drain Current



Vds Drain-Source Voltage (V)

Figure 5 Output Characteristics



I<sub>D</sub>- Drain Current (A)

Figure 6 Rdson vs Drain Current

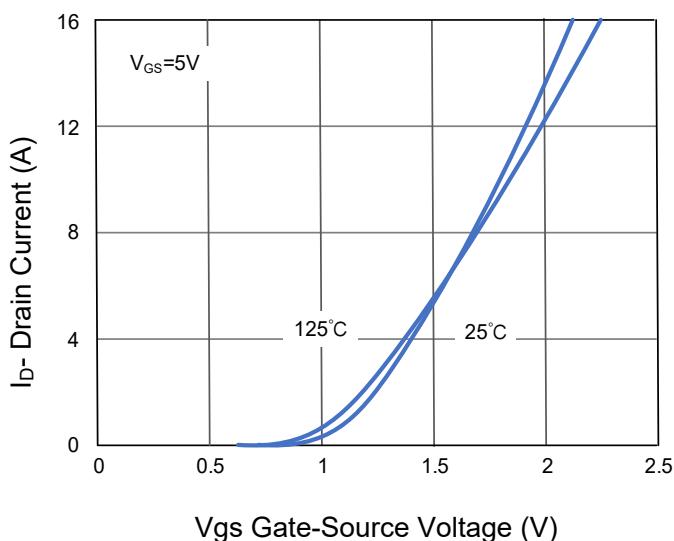


Figure 7 Transfer Characteristics

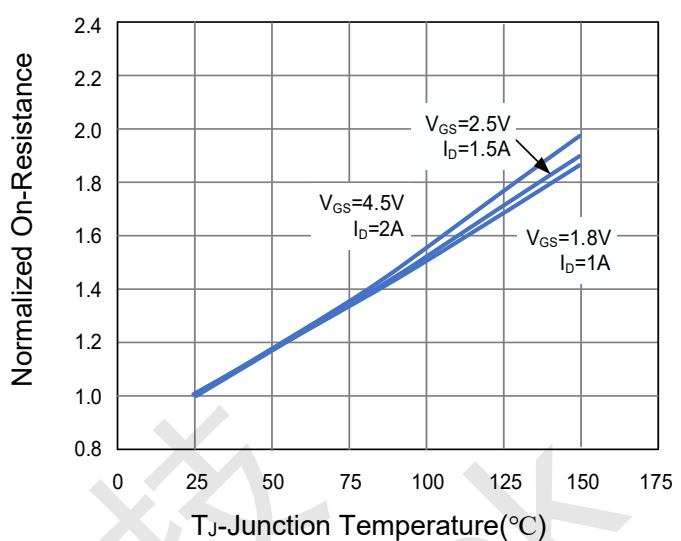


Figure 8  $R_{DSON}$  vs Junction Temperature

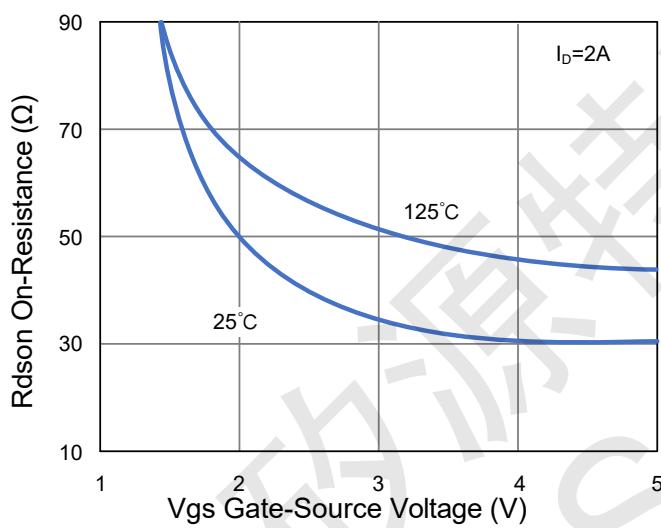


Figure 9  $R_{DSON}$  vs  $V_{GS}$

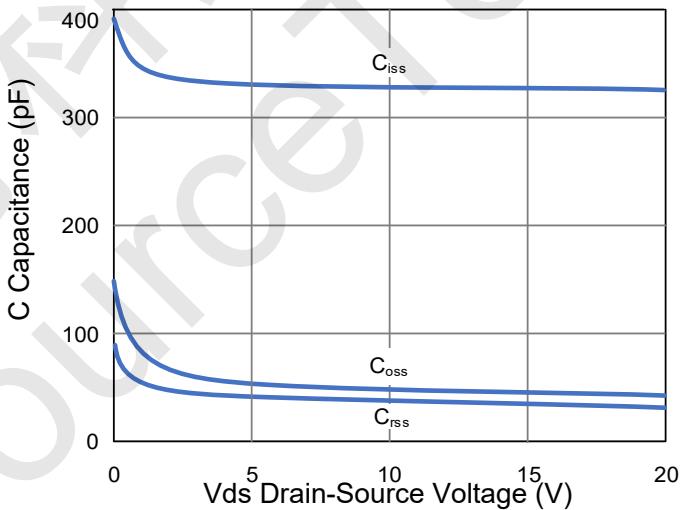


Figure 10 Capacitance vs  $V_{DS}$

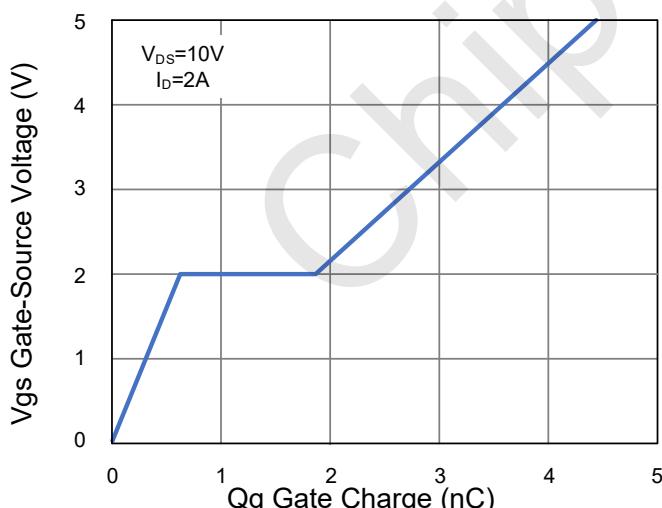


Figure 11 Gate Charge

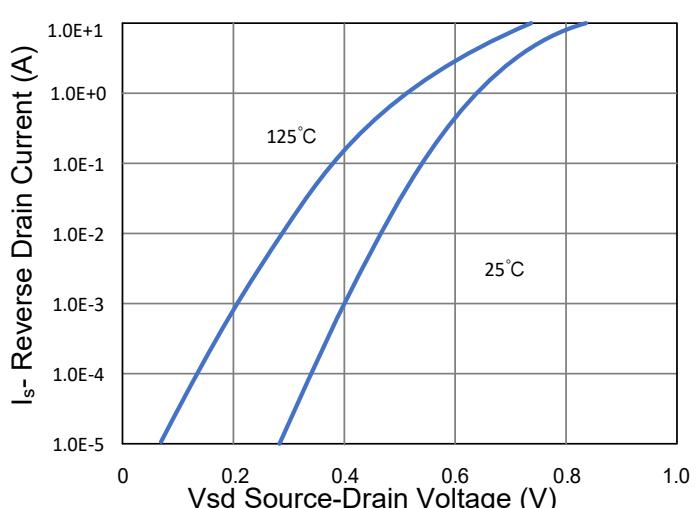


Figure 12 Source-Drain Diode Forward

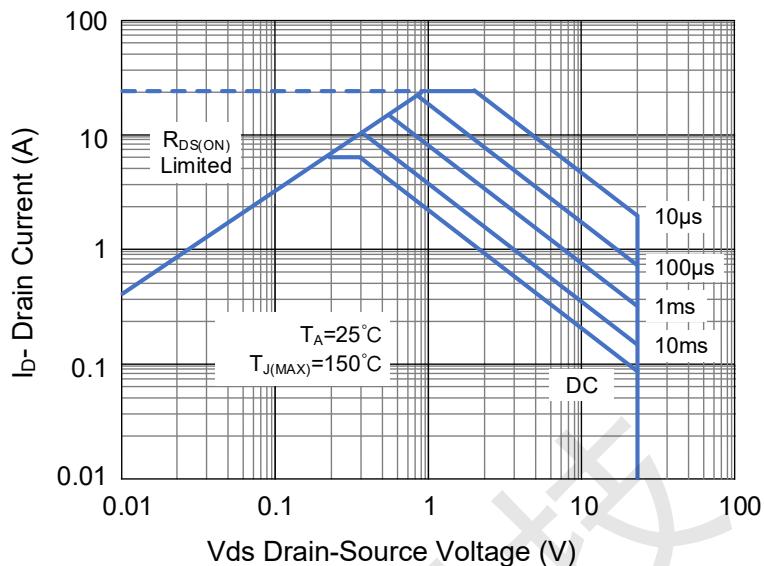


Figure 13 Safe Operation Area

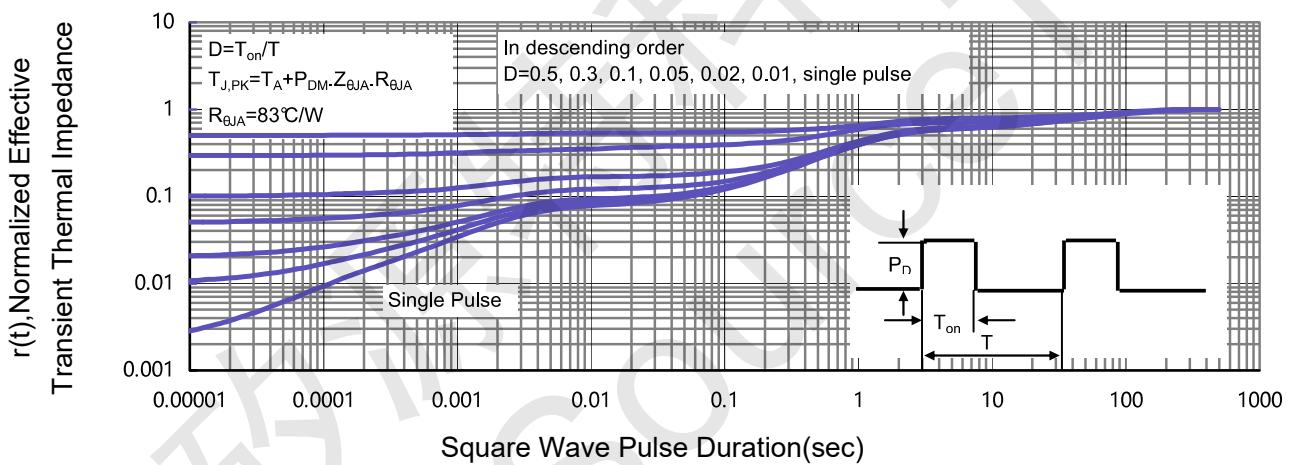
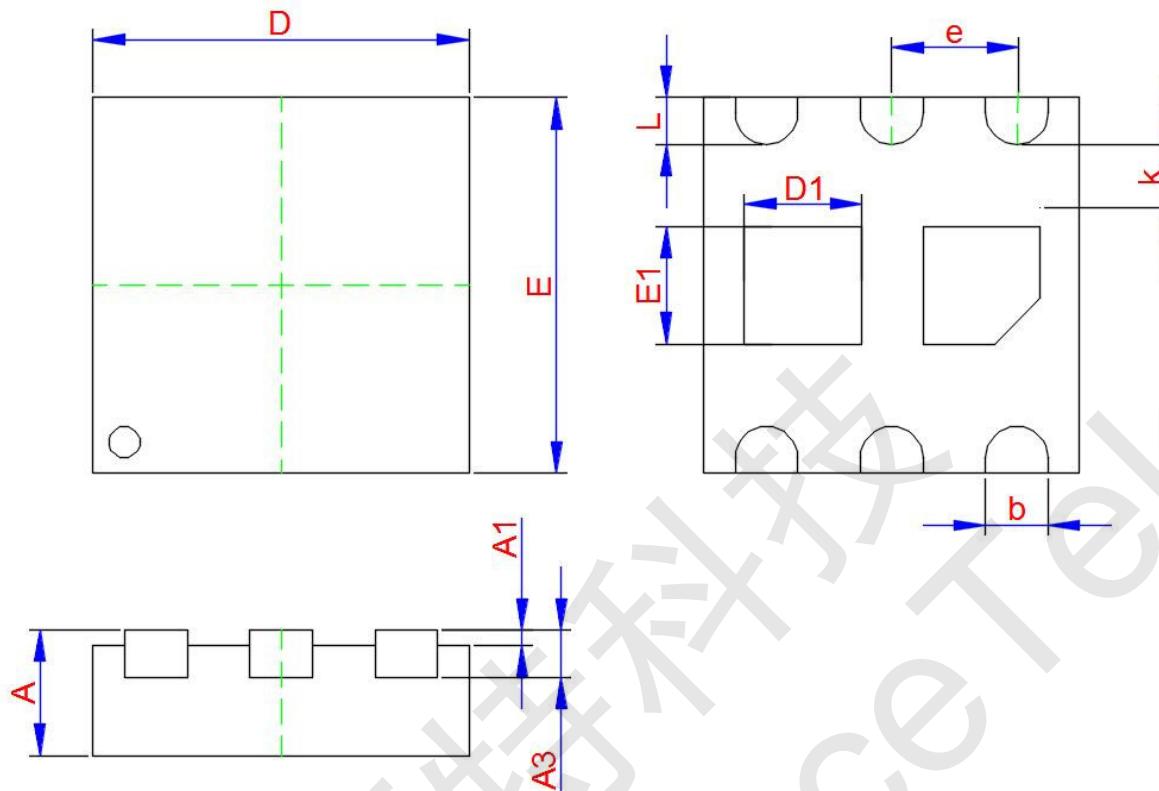


Figure 14 Normalized Maximum Transient Thermal Impedance



## PE2302DF DFN2x2-6L Package Information



Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	0.700	0.750	0.800
A1	-	0.020	0.050
A3	0.170	0.200	0.230
D	1.950	2.000	2.050
E	1.950	2.000	2.050
D1	0.500	0.550	0.600
E1	0.850	0.900	0.950
b	0.200	0.250	0.300
L	0.275	0.300	0.325
k	0.200MIN.		
e	0.650TYP.		